NSN 5961-01-376-4988

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-376-4988 **Inclosure Material:** Metal **Overall Length:** 0.300 inches **Terminal Length:** 0.980 inches **Overall Diameter:** 0.450 inches **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 28.0 reverse voltage, total rms and 40.0 repetitive peak reverse voltage and 40.0 working peak reverse voltage and 40.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 15.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: